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NLX1G125

Non-Inverting 3-State Buffer

The NLX1G125 is an advanced high−speed 2−input CMOS non−inverting 3−state buffer in ultra−small footprint.

The NLX1G125 input structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

Features

- High Speed: t_{PD} = 2.7 ns (Typ) @ V_{CC} = 5.0 V
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Low Power Dissipation: I_{CC} = 1 μA (Max) at T_A = 25°C
- 24 mA Balanced Output Source and Sink Capability
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input Pins
- Ultra−Small Packages
- These are Pb−Free Devices

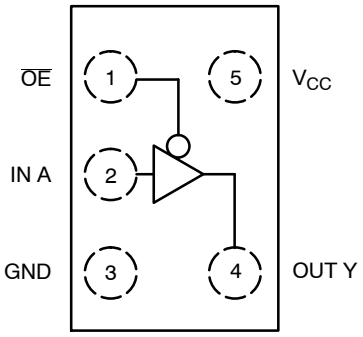

Figure 1. Pinout (Top View)

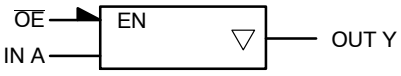

Figure 2. Logic Symbol

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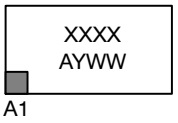
MARKING DIAGRAM

5 PIN FLIP−CHIP CASE 499BG



XXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week

PIN ASSIGNMENT	
1	$\overline{OE}$
2	IN A
3	GND
4	OUT Y
5	V_{CC}

FUNCTION TABLE

A Input	$\overline{OE}$ Input	Y Output
L	L	L
H	L	H
X	H	Z

X = Don't Care

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

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MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage		−0.5 to +7.0	V
V_{IN}	DC Input Voltage		−0.5 to +7.0	V
V_{OUT}	DC Output Voltage		−0.5 to +7.0	V
I_{IK}	DC Input Diode Current	V_{IN} < GND	−50	mA
I_{OK}	DC Output Diode Current	V_{OUT} < GND	−50	mA
I_{OUT}	DC Output Sink Current		±50	mA
I_{CC}	DC Supply Current per Supply Pin		±100	mA
I_{GND}	DC Ground Current per Ground Pin		±100	mA
T_{STG}	Storage Temperature Range		−65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds		TBD	°C
T_J	Junction Temperature Under Bias		TBD	°C
θ_{JA}	Thermal Resistance (Note 1)		TBD	°C/W
P_D	Power Dissipation in Still Air at 85°C		TBD	mW
MSL	Moisture Sensitivity		Level 1	
F_R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V−0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	>2000 >200 N/A	V
$I_{LATCHUP}$	Latchup Performance Above V_{CC} and Below GND at 125 °C (Note 5)		±500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm−by−1 inch, 2 ounce copper trace with no air flow.
2. Tested to EIA/JESD22−A114−A.
3. Tested to EIA/JESD22−A115−A.
4. Tested to JESD22−C101−A.
5. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Positive DC Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	V
V_{IN}	Digital Input Voltage (Note 6)		0	5.5	V
V_{OUT}	Output Voltage		0	5.5	V
T_A	Operating Free−Air Temperature		−55	+125	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate	V_{CC} = 1.8 V ± 0.15 V V_{CC} = 2.5 V ± 0.2 V V_{CC} = 3.3 V ± 0.3 V V_{CC} = 5.0 V ± 0.5 V	0 0 0 0	20 20 10 5.0	ns/V

6. Unused inputs may not be left open. All inputs must be tied to a high or low−logic input voltage level.

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25 °C			T_A = −55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	
V_{IH}	Low−Level Input Voltage		1.65	0.75 x V_{CC}			0.75 x V_{CC}		V
			2.3 to 5.5	0.70 x V_{CC}			0.70 x V_{CC}		
V_{IL}	Low−Level Input Voltage		1.65			0.25 x V_{CC}		0.25 x V_{CC}	V
			2.3 – 5.5			0.30 x V_{CC}		0.30 x V_{CC}	
V_{OH}	High−Level Output Voltage	V_{IN} = V_{IH} or V_{IL} I_{OH} = −100 μA	1.65 – 5.5	V_{CC}−0.1	V_{CC}		V_{CC}−0.1		V
		V_{IN} = V_{IH} or V_{IL} I_{OH} = −4 mA I_{OH} = −8 mA I_{OH} = −12 mA I_{OH} = −16 mA I_{OH} = −24 mA I_{OH} = −32 mA	1.65 2.3 2.7 3.0 3.0 4.5	1.29 1.9 2.2 2.4 2.3 3.8	1.52 2.15 2.4 2.8 2.68 4.2		1.29 1.9 2.2 2.4 2.3 3.8		
V_{OL}	Low−Level Output Voltage	V_{IN} = V_{IH} or V_{IL} I_{OL} = 100 μA	1.65 – 5.5			0.1		0.1	V
		V_{IN} = V_{IH} or V_{IL} I_{OH} = 4 mA I_{OH} = 8 mA I_{OH} = 12 mA I_{OH} = 16 mA I_{OH} = 24 mA I_{OH} = 32 mA	1.65 2.3 2.7 3.0 3.0 4.5		0.08 0.1 0.12 0.15 0.22 0.22	0.24 0.3 0.4 0.4 0.55 0.55		0.24 0.3 0.4 0.4 0.55 0.55	
I_{IN}	Input Leakage Current	0 ≤ V_{IN} ≤ 5.5V	0 to 5.5			±0.1		±1.0	μA
I_{OZ}	3−State Output Leakage Current	V_{IN} = V_{IH} or V_{IL} 0 ≤ V_{OUT} ≤ 5.5V	0			±0.5		±5.0	μA
I_{OFF}	Power−Off Output Leakage Current	V_{IN} = 5.5 V	0			1.0		10	μA
I_{CC}	Quiescent Supply Current	0 ≤ V_{IN} ≤ V_{CC}	5.5			1.0		10	μA

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AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 2.5$ ns)

Symbol	Parameter	V_{CC} (V)	Test Condition	T_A = 25 °C			T_A = −55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay, Input to Output (Figures 3 and 4, Table 1)	1.65–1.95	R_L = 1 MΩ, C_L = 15 pF	2.0	6.0	10	2.0	10.5	ns
		2.3–2.7	R_L = 1 MΩ, C_L = 15 pF	1.0	3.4	7.5	1.0	8.0	
		3.0–3.6	R_L = 1 MΩ, C_L = 15 pF	0.8	2.5	5.2	0.8	5.5	
			R_L = 500 Ω, C_L = 50 pF	1.2	3.1	5.7	1.2	6.0	
		4.5–5.5	R_L = 1 MΩ, C_L = 15 pF	0.5	1.8	4.5	0.5	4.8	
			R_L = 500 Ω, C_L = 50 pF	0.8	2.3	5.0	0.8	5.3	
t_{PZH}, t_{PZL}	Output Enable Time (Figures 5, 6and 7, Table 1)	1.65–1.95	R_L = 250 Ω, C_L = 50 pF	2.0	7.6	9.5	2.0	10	ns
		2.3–2.7		1.8		8.5	1.8	9.0	
		3.0–3.6		1.2		6.2	1.2	6.5	
		4.5–5.5		0.8		5.5	0.8	5.8	
t_{PHZ}, t_{PLZ}	Output Disable Time (Figures 5, 6and 7, Table 1)	1.65–1.95	R_L = R_1 = 5–0 Ω, C_L = 50 pF	2.0	8.0	10	2.0	10.5	ns
		2.3–2.7		1.5		8.0	1.5	8.5	
		3.0–3.6		0.8		5.7	0.8	6.0	
		4.5–5.5		0.3		4.7	0.3	5.0	
C_{IN}	Input Capacitance	5.5	V_{IN} = 0 V or V_{CC}		2.5				pF
C_{OUT}	Output Capacitance	5.5	V_{IN} = 0 V or V_{CC}		2.5				pF
C_{PD}	Power Dissipation Capacitance (Note 7)	3.3 5.5	10 MHz V_{IN} = 0 V or V_{CC}		9.0 11				pF

7. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no−load dynamic power consumption: $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

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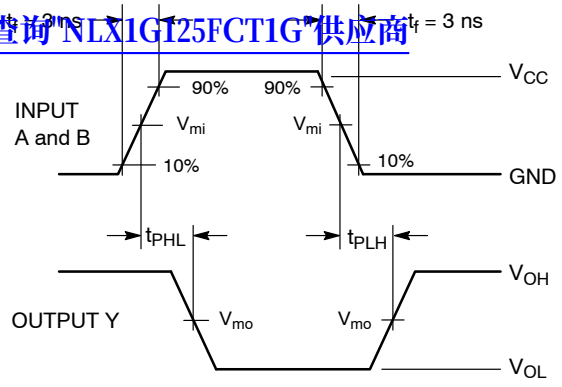
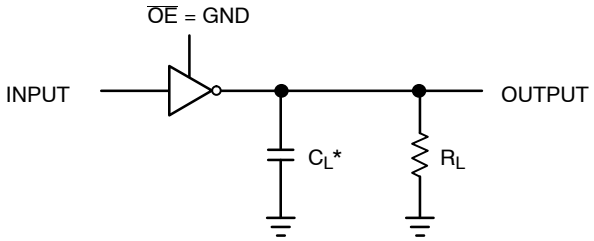
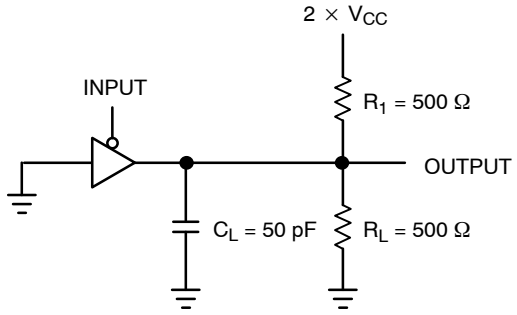


Figure 3. Switching Waveform



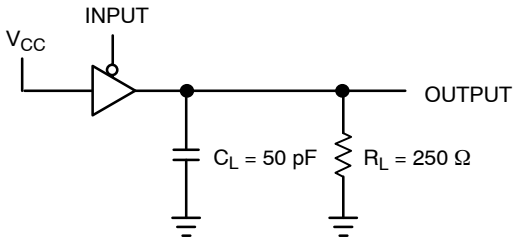
*Includes all probe and jig capacitance.
A 1 MHz square input wave is recommended for propagation delay tests.

Figure 4. T_{PLH} or T_{PHL}



A 1 MHz square input wave is recommended for propagation delay tests.

Figure 5. T_{PZL} or T_{PL}



A 1 MHz square input wave is recommended for propagation delay tests.

Figure 6. T_{PZH} or T_{PHZ}

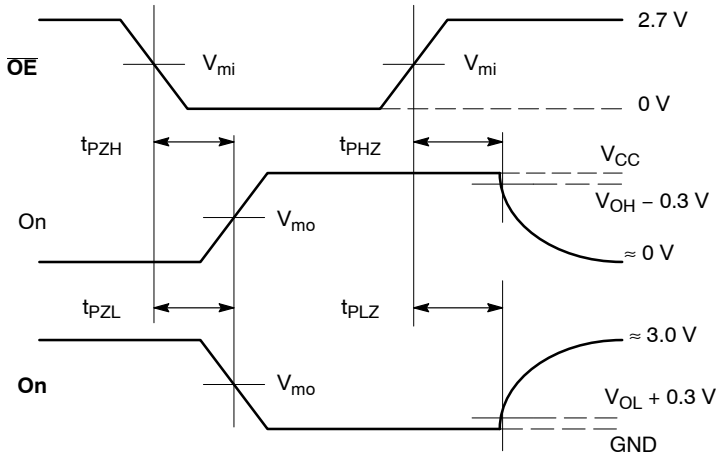


Figure 7. AC Output Enable and Disable Waveform

Table 1. OUTPUT ENABLE AND DISABLE TIMES

$t_R = t_F$ = 2.5 ns, 10% to 90%; f = 1 MHz; t_W = 500 ns

Symbol	V_{CC}		
	3.3 V ± 0.3 V	**2.7 V**	**2.5 V ± 0.2 V**
V_{mi}	1.5 V	1.5 V	$V_{CC}/2$
V_{mo}	1.5 V	1.5 V	$V_{CC}/2$

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DEVICE ORDERING INFORMATION

Device	Package	Shipping†
NLX1G125FCT1G	Flip−Chip 5 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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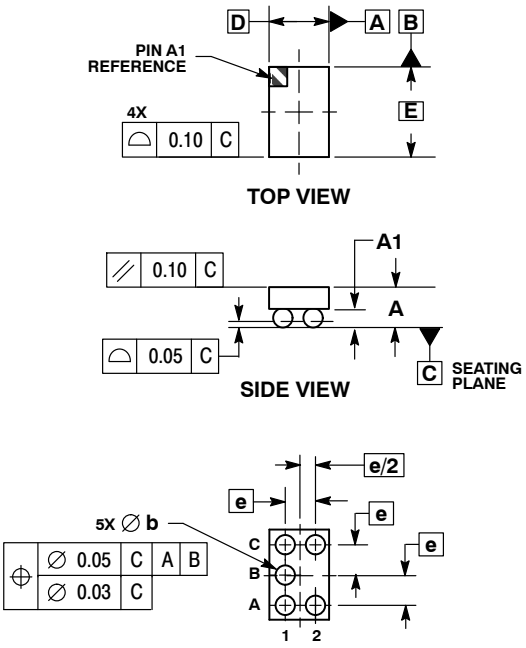
PACKAGE DIMENSIONS

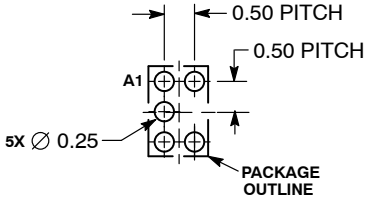
5 PIN FLIP−CHIP
CASE 499BG−01
ISSUE O



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

	MILLIMETERS	
DIM	MIN	MAX
A	0.44	0.50
A1	0.15	0.19
b	0.21	0.25
D	0.90 BSC	
E	1.40 BSC	
e	0.50 BSC	

SOLDERING FOOTPRINT*



*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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